

Parity-time symmetry single-mode double-microdisk InGaAs quantum dot lasers

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We successfully demonstrate the parity-time symmetry (PT-symmetry) single-mode lasing operation of laterally coupled double-microdisk lasers. The microdisk lasers of disk diameter = 2.85 μm are fabricated by using MBE-grown InGaAs quantum dots as the gain medium. The gain materials of dots-in-a-well (DWELL) structures are grown on (001) n^+ -GaAs substrate by molecular beam epitaxy. The wafer structure consists of a 1 μm -thick $\text{Al}_{0.5}\text{Ga}_{0.5}\text{As}$ sacrifice layer, and an active layer comprised of a stack of six InGaAs DWELLS. In spite of the lasing output of multiple whispering-gallery modes (WGMs) from the single microdisk lasers, the laterally coupled double-microdisk lasers achieve single WGM lasing under gain-loss contrast pumping condition, literally pumping only one disk for the double- microdisk. We change the air gap distance (d) for the coupled double-microdisk structures to change the coupling strength (k) between the microdisks. Under single selective pumping (gain-loss contrast) at room temperature, the laterally coupled double microdisk lasers of $d = 150\text{nm}$, and 200nm show single lasing mode at WGM $m = 1, 21$ ($\lambda = 1199\text{nm}$). We also fabricate the double-microdisk lasers by coating the microdisks with HfO_2 to change the coupling strength k . Under single selective pumping, the HfO_2 -coated double microdisk lasers show a single lasing mode at WGM $m = 1, 20$ ($\lambda = 1277\text{nm}$).

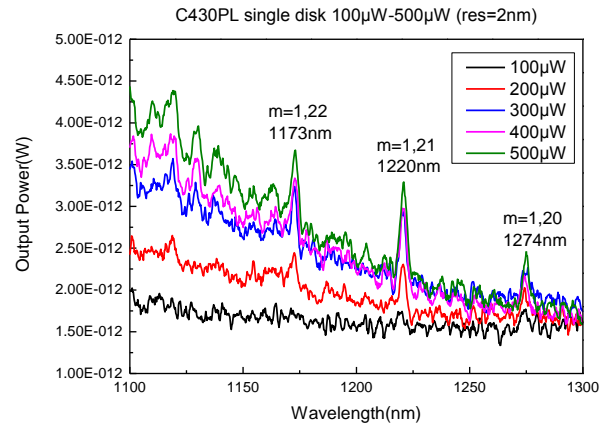
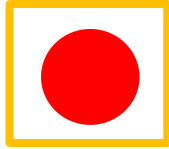
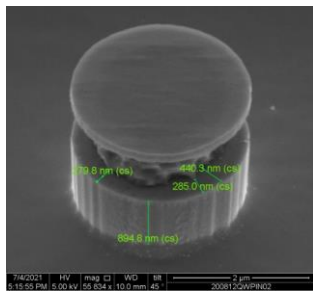


Fig. 1. SEM picture for a single microdisk of diameter = 2.85 μm , and the lasing output of multiple WGMs .

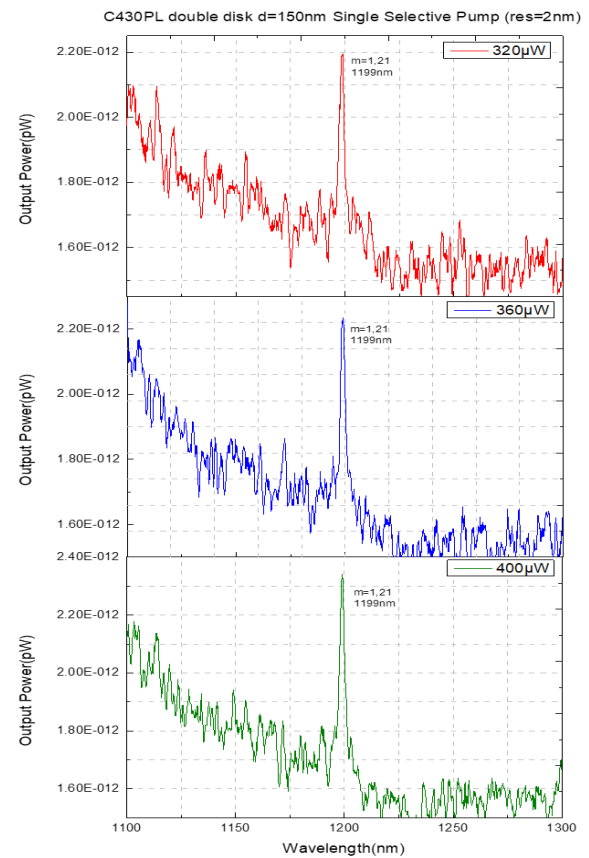
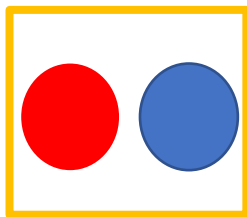
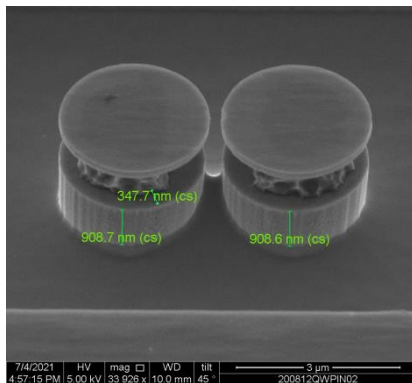


Fig. 2. Under single selective pumping (gain-loss contrast) at room temperature, single lasing mode at WGM $m = 1,21$ ($\lambda = 1199\text{nm}$) is obtained for the laterally coupled double- microdisk laser of $d = 150\text{nm}$.